

Rev. V1

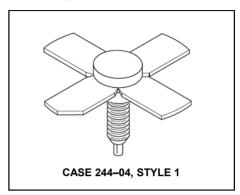
Designed primarily for wideband large—signal driver and predriver amplifier stages in the 200–500 MHz frequency range.

- Guaranteed performance at 400 MHz, 28 V
 Output power = 20 W
 Power gain = 10 dB min.
 Efficiency = 50% min.
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Gold metallization system for high reliability
- Computer-controlled wirebonding gives consistent input impedance

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	33	Vdc
Collector-Base Voltage	V _{CBO}	60	Vdc
Emitter–Base Voltage	V _{EBO}	4.0	Vdc
Collector Current — Continuous — Peak	I _C	2.2 3.0	Adc
Total Device Dissipation @ T _C = 25°C (1) Derate above 25°C	P _D	55 310	Watts mW/°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Product Image



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	3.2	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	<u> </u>	•	•	•	•
Collector–Emitter Breakdown Voltage (I _C = 20 mAdc, I _B = 0)	V _(BR) CEO	33	_	_	Vdc
Collector–Emitter Breakdown Voltage (I _C = 20 mAdc, V _{BE} = 0)	V _{(BR)CES}	60	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 20 mAdc, I _E = 0)	V _(BR) CBO	60	_	_	Vdc
Emitter–Base Breakdown Voltage (I _E = 2.0 mAdc, I _C = 0)	V _{(BR)EBO}	4.0	_	_	Vdc
Collector Cutoff Current (V _{CB} = 30 Vdc, I _E = 0)	I _{CBO}	_	_	2.0	mAdc
ON CHARACTERISTICS	•	•	+	•	•
DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	h _{FE}	20	_	80	_

NOTE: (continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

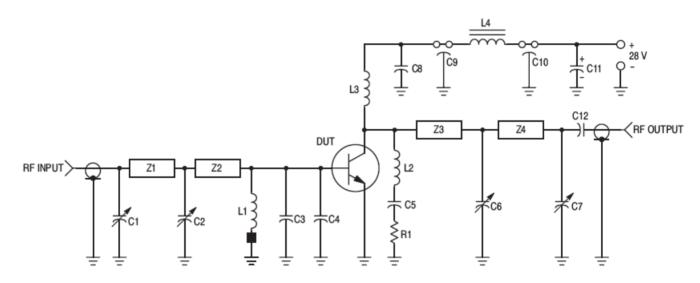
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ELECTRICAL CHARACTERISTICS — continued (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
DYNAMIC CHARACTERISTICS	•	•		•	
Output Capacitance (V _{CB} = 28 Vdc, I _E = 0, f = 1.0 MHz)	C _{ob}	_	20	24	pF
FUNCTIONAL TESTS (Figure 1)	•			•	
Common–Emitter Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 20 W, f = 400 MHz)	G _{PE}	10	11	_	dB
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 20 W, f = 400 MHz)	η	50	60	_	%
Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 20 W, f = 400 MHz, VSWR = 30:1 all phase angles)	Ψ	No Degradation in Output Power			



C1, C2, C6 — 1.0-20 pF Johanson Trimmer (JMC 5501)

C3, C4 - 47 pF ATC Chip Capacitor

C5, C8 — 0.1 µF Erie Redcap

C7 — 0.5-10 pF Johanson Trimmer (JMC 5201)

C9, C10 - 680 pF Feedthru

C11 - 1.0 µF 50 Volt Tantalum

C12 - 0.018 µF Vitramon Chip Capacitor

L1 — 0.33 μH Molded Choke with Ferroxcube Bead (Ferroxcube 56–590–65/4B) on Ground End L2 - 6 Turns #20 Enamel, 1/4" ID, Closewound

L3 - 4 Turns #20 Enamel, 1/8" ID, Closewound

L4 — Ferroxcube VK200-19/4B

R1 — 5.1 Ω 1/4 Watt

Z1 - Microstrip 0.1" W x 1.35" L

Z2 - Microstrip 0.1" W x 0.55" L

Z3 — Microstrip 0.1" W x 0.8" L

Z4 — Microstrip 0.1" W x 1.75" L

Board — Glass Teflon ε_r = 2.56, t = 0.062"

Input/Output Connectors — Type N

Figure 1. 400 MHz Test Circuit Schematic



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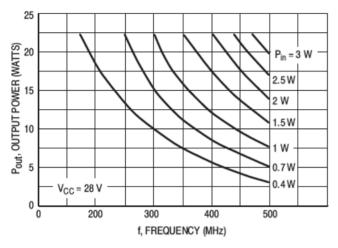
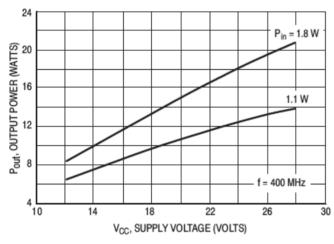


Figure 2. Output Power versus Frequency

Figure 3. Output Power versus Input Power



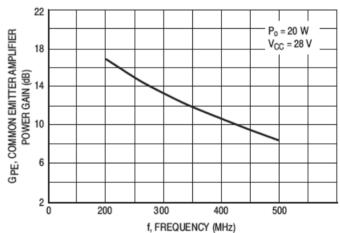
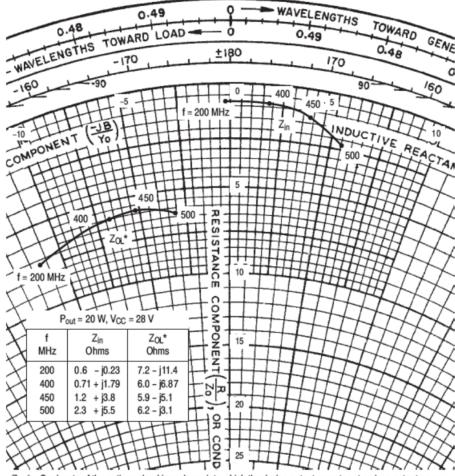


Figure 4. Output Power versus Supply Voltage

Figure 5. Power Gain versus Frequency



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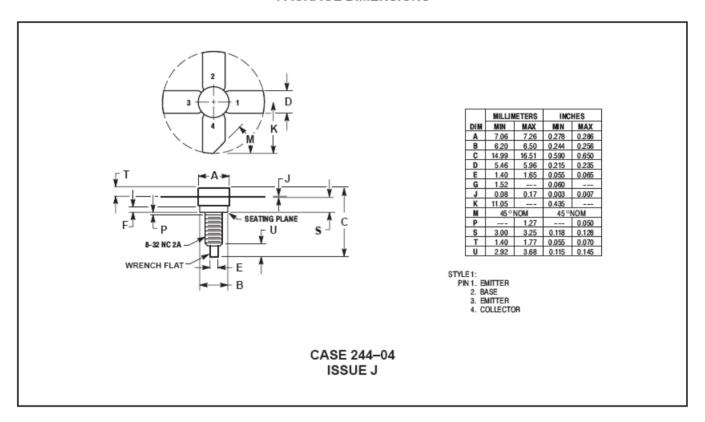
Z_{OL}* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 6. Series Equivalent Impedance



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PACKAGE DIMENSIONS



MRF323



The RF Line NPN Silicon Power Transistor 20W, 400MHz, 28V

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